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ELECTRONIC PROPERTIES OF ZIG-ZAG CARBON NANOTUBES: A FIRST-

PRINCIPLES STUDY

By

PAVAN KUMAR VALAVALA

A THESIS

Submitted in partial fulfillment of the requirements

for the degree of

MASTER OF SCIENCE

(Physics)

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2008

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Abstract

Carbon nanotube (CNT) is a one dimensional (1-D) nanostructured material, which has been the focal point of research over the past decade for intriguing applications ranging from nanoelectronics to chemical and biological sensors. Using a first-principles gradient corrected density functional approach, we present a comprehensive study of the geometry and energy band gap in zig-zag semi-conducting (n,0) carbon nanotubes (CNT) to resolve some of the conflicting findings. Our calculations confirm that the single wall (n,0) CNTs fall into two distinct classes depending upon $n \mod 3$ equal to 1 (smaller band gaps) or 2 (larger gaps). The effect of longitudinal strain on the band gap further confirms the existence of two distinct classes: for $n \mod 3 = 1$ or 2, changing E_g by ~ ±110 meV for 1% strain in each case. We also present our findings for the origin of metallicity in multiwall CNTs.

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Chapter 1

Introduction

Since the beginning of civilization, materials have defined substantially periods of history that brought about insurmountable changes through the use of certain materials. Archeologists broadly classify prehistory into three eras: the Stone Age, the Bronze Age, and the Iron Age [1]. Each period is known for advancements enabled by the efficient use of materials as tools that shaped the contemporary world. The Stone Age is characterized by the use of tools crafted from stone that assisted primitive civilizations to hunt and gather food. The Bronze Age was dominated by the use of copper and bronze and was led to the inception of metalworking. The Iron Age is marked by the widespread use of cast iron tools for various activities. It is undisputable that materials play a vital role in the advancement of the quality of human life. The evolution of global connectivity has heavily relied on the use of solid-state devices in various electronics.

One of the primary focuses of contemporary research is to understand matter from a fundamental standpoint that can potentially lead to designing many novel devices and structures. Nanoscience refers to the study of matter at the atomic or molecular scale (typically 100 nm or smaller). Nanoscience has opened doors to many fields of interdisciplinary research spanning the entire spectrum from basic sciences to engineering. In 1959, Nobel laureate Richard P. Feynman delivered a talk at the American Physical Society at Caltech titled "There's plenty of room at the bottom"[2]. This lecture was a solicitation to the innumerable opportunities in the uncharted area of nanoscience.

1.1 CARBON NANOMATERIALS

Nanomaterial is a term used broadly for materials that have been synthesized to possess a certain characteristics by design at the namometer scale to achieve certain desired properties. In 1985, a group of five scientists from Rice University discovered a new carbon allotrope known as "C₆₀: Buckminsterfullerene"[3]. This work was awarded the Nobel prize in Chemistry in 1996 [4]. Following the discovery of "fullerenes", in 1991 a Japanese scientist discovered carbon nanotube (also considered an allotrope of carbon) [5]. A Carbon nanotube (CNT) is a one dimensional (1-D) nanostructured material, which has been the focal point of research over the past decade for intriguing applications ranging from nanoelectronics to chemical and biological sensors. The geometry of the carbon nanotube is uniquely described by a chiral vector $(\vec{C}):\vec{C} = n\vec{a} + m\vec{b}$, denoted by a pair of indices (*n*, *m*) that connect the two crystallographically equivalent sites on the graphene sheet (a single layer of graphite). CNTs can be classified based on the chiral indices (*n*, *m*) that define its geometry. When either *n* or *m* is equal to zero, rolling a graphene sheet results in a "zig-zag" CNT. In cases, when n = m, the resultant CNT is known have an "armchair" configuration, all the other cases when $(n \neq m)$ is referred to as "chiral" structure. Figure 1.1 is a graphic representation of the various kinds of CNT based on its geometry. In addition to C₆₀ and CNT, other forms of carbon include diamond, graphite, and amorphous carbon.

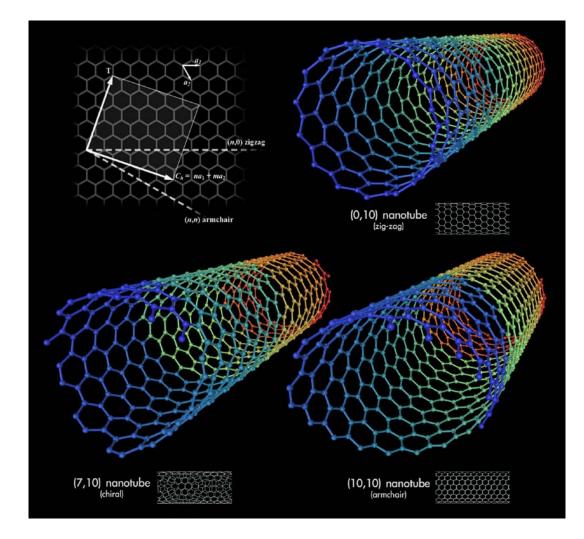


Figure 1.1 A graphic representation of different kinds of CNT based on its chiral indices (*n*,*m*) (accessed on July 10, 2008; Copyright - Michael Ströck, Wikimedia Commons, 2006, distributed under GFDL, refer Appendix A for permission) [6]

1.2 APPLICATIONS OF CARBON NANOTUBES

It was reported that depending on the chirality of the CNT its electronic properties change. It was also found that it possessed exceptional mechanical, electrical and optical properties that made it an excellent candidate for numerous applications that spawned a great interest in this form of carbon.

A. Structural Applications

Due to their chemical structure honeycomb arrangement of the carbon atoms and a extremely high degree of symmetry CNTs possess excellent mechanical properties. It is found that the strength and stiffness of this material far exceeds that of steel and ability to withstand much larger strains to failure resulting is extremely tough behavior [7-9]. Also, carbon nanotubes are much lighter than steel making them ideal for reinforcements in polymer matrix composites [10-15]. Some interesting application for CNT have suggested in view of its exceptional mechanical properties such as the space elevator.

B. Electronics Applications

CNTs posses' unique characteristics in terms of their electronic properties, the chilarity of a CNT determines its eventual properties. This unique dependence makes it conducive to certain applications in nanoscale electronics or molecular electronics. In addition, it has also been shown that CNT can be used a capacitor that has potential for 11

commercial batteries [16]. Researchers have also found excellent field emission (emission of electrons from surface in presence of high electric fields) properties for CNT making it ideal for microelectronic devices and certain advanced microscopy techniques [17]. It is also tolerant to faults without significant impact on its performance when compared to silicon.

C. Chemical and Biological Applications

Single walled CNTs show significant changes in their electrical properties when exposed to certain chemical environments making them suitable for chemical sensing. It was also reported that these devices exhibit much higher sensitivity than the current solid-state sensors used for the application [18].

An understanding of binding of certain molecules to specific proteins can pave the road for deigning novel medicine or molecular medicine. An extremely high aspect ratio of the CNT provides a large surface area for effective detection of certain biomolecules even at a very low concentration making it ideal for applications such as drug delivery [19]. The applications of CNT in biology are not restricted to sensing, self powered artificial muscles and prosthetics are envisioned to be potential applications [20]. It has been reported that CNT based artificial muscles for robotics applications can be manufactured from sheets of CNT that can store energy while not in use due its function as a capacitor [21].

1.3 OBJECTIVE

One of the central requirements for a device to operate according to predetermined design relies on *apriori* accurate knowledge of the characteristics of the components. Numerous applications for CNTs rely on its novel electrical properties and experimental determination of their chiralities and measurement of their diameters has been a challenge. These characteristics are crucial to its overall performance as they can vary significantly. A third of the single walled CNTs are metallic while the rest are semiconducting. It is extremely difficult to control the chiralities of the CNTs as grown in laboratory. A vital part of the manufacture process is characterization of the synthesized tubes. The experimental measurements fall within the accuracy of the measuring techniques making it extremely difficult to make a unique characterization. However, *apriori* information of their properties can aide in design of reliable and efficient characterization as well as purification processes. Computational solid-state physics provides the tools to probe the properties of these materials with minimal experimental data. Computational studies in conjunction with experiments can help exploit the potential of CNTs. The objective of the current research is to explore certain aspects of the electronic properties of CNTs via *first-principles* simulations. First, the exact dependence of chirality of a zig-zag semiconducting CNT on its energy band gap will be explored. And second, the role of the electronic properties of individual wall of a multiwall CNT on its overall behavior will be presented.

Chapter 2

First-Principles Simulation

Techniques

Condensed matter physics is a field of physical science that is used to describe the study of matter in its "condensed" state generally associated with solids and liquid phase materials. One of the categories in this area that strives to understand matter in solid phase is known as solid-state physics. This discipline of science relies on a large number of experimental, theoretical and computational techniques to probe the properties to better understand materials. An area that involves extensive use of computational techniques is exploring electronic properties of solid state matter. Electronic properties can be studied at various length scales spanning from macro-scale to sub-atomic scales with distinct characteristics at every length scale. Many physical and chemical properties manifested at the macroscale can be related back to the arrangement of electrons at the atomic scale.

In the beginning of the 20th century, physicists were struggling to explain certain experimentally observed phenomenon as black body radiation and spectrum of certain

atoms using classical or Newtonian mechanics. Classical mechanics is extremely successful in describing the working of the macroscale however; these rules were violated at the smaller length scale and anomalies were observed. This behavior of matter at atomic and sub-atomic scales demanded the formulation of a theory that is capable of describing experimentally results. Over the next few decades a number of physicists have been able to comprehend experimental observations based on "quantum mechanics". Quantum mechanics is a probabilistic description of mechanical systems at the atomic and subatomic scales.

2.1 SCHRÖDINGER EQUATION

One of the corner stone's of quantum mechanics is the Schrödinger equation, which a fundamental description of time evolution of quantum state of a system. This opened doors to a more comprehensive understanding of physical and chemical properties of matter. Equation (2.1) represents a time independent Schrödinger equation. In the context of electrons, Schrödinger equation represents a wavefunction. Equation (2.2) is the Hamiltonian for a many body problem neglecting the relativistic effects. Despite its ability to explain many interesting phenomenon, the Schrödinger equation cannot be solved in closed form beyond one-electron systems severely restricting its application. Most solids are rather large systems with multiple molecules that are made of atoms that in turn consist of numerous electrons. The solution of Schrödinger equation for such systems holds the key to its properties, this many body problem does not have an

analytic solution. To circumvent this problem, one has to rely on approximate solutions to the Schrödinger equation.

$$\hat{H} |\Psi\rangle = E |\Psi\rangle \tag{2.1}$$

where, H is the Hamiltonian operator, E is the energy eigenvalue of the system and $|\Psi\rangle$ is the electron wave function. For a general case where Ψ represents a *N*-electron wavefunction $|\Psi\rangle = \Psi(\vec{r}_1, \vec{r}_2, ..., \vec{r}_N)$.

$$\hat{H} = -\sum_{i} \frac{1}{2} \nabla_{i}^{2} - \sum_{K} \frac{1}{2M_{K}} \nabla_{K}^{2} - \sum_{i,K} \frac{Z_{K}}{\left|\vec{r_{i}} - \vec{R}_{K}\right|} + \sum_{i>j} \frac{1}{\left|\vec{r_{i}} - \vec{r_{j}}\right|} + \sum_{K>L} \frac{Z_{K}Z_{L}}{\left|\vec{R}_{K} - \vec{R}_{L}\right|} \quad (2.2)$$

where, the terms involving ∇^2 represent the kinetic energies of the electrons and nuclei for the subscript *i* and *K* respectively. *Z* represents the number of protons in the nuclei; *r* and *R* are the position vectors for the nuclei and the electron respectively. *M* is the mass of the nucleus.

2.2 BORN-OPPENHEIMER APPROXIMATION

The Schrödinger equation in its time-independent non-relativistic form involves the kinetic energy of the nuclei of the physical system. It is well known that the mass of an atom is primarily concentrated in its nucleus and the electrons constitute a very minor percentage of the overall mass of the atom. In most cases, the speeds which the electrons orbit the nucleus is much higher than the speed at which the nucleus is moving. In light of these observations, it can argued that the kinetic energy of the nuclei 16

have a very negligible contribution to the overall energy of the system and hence can be ignored. In the absence of nuclear kinetic energy, equation (2.2) can be written as.

$$\hat{H} = \hat{T}_e + \hat{J} \tag{2.3}$$

where, \hat{T}_e is the kinetic energy of the electrons in the system and \hat{J} represents the Coulombic interactions including electron-electron, nucleus-nucleus and nucleus-electron interactions.

In essence, Born-Oppenheimer approximation freezes the nuclei in space and thereby creating a constant potential. Equation (2.3) reduces the complexity of the many body problem, however, it still does not lend itself to be solved in closed form, many approximations have been proposed and are required for a solution to this highly coupled problem. Some of the widely accepted methods are discussed in the following sections.

2.3 HARTREE-FOCK METHOD

The solution of the Schrödinger equation to these complex physical systems can be obtained from various methods. Each of these methods provide certain strengths and weakness making them suitable for specific applications and the level of complexity involved in applying these methods also varies. Soon after the Schrödinger proposed the wave equation in 1926, Douglas Hartree introduced a numerical procedure to solve the Schrödinger's equation; he proposed that the many body wavefunction can be written as a product of the hydrogen like wavefunctions. It is analogous to the linear combination of atomic orbitals (LCAO) methodology employed in some calculated today. This came to be known as the Hartree product and the procedure was termed the self-consistent field method. However, it did not take the principle of anti-symmetry (put forth by Wolfgang Pauli for fermions) of the electron wavefunction into account. It was later shown that if the one particles wavefunctions are assembled in a matrix form, the resulting wavefunction satisfied the requirements of Pauli's exclusion principle. This came to be known as the 'Slater determinant'. The Slater determinant for an *N* electron system can be written as follows:

$$\left| \Psi \left(\vec{r}_{1}, \vec{r}_{2}, \dots, \vec{r}_{N} \right) \right\rangle = \frac{1}{\sqrt{N!}} \left| \begin{array}{cccc} \psi_{1} \left(\vec{r}_{1} \right) & \psi_{2} \left(\vec{r}_{1} \right) & \cdots & \psi_{N} \left(\vec{r}_{1} \right) \\ \psi_{1} \left(\vec{r}_{2} \right) & \psi_{2} \left(\vec{r}_{2} \right) & \cdots & \psi_{N} \left(\vec{r}_{2} \right) \\ \vdots & \vdots & \ddots & \vdots \\ \psi_{1} \left(\vec{r}_{N} \right) & \psi_{2} \left(\vec{r}_{N} \right) & \cdots & \psi_{N} \left(\vec{r}_{N} \right) \end{array} \right|$$
(2.4)

where $\psi_i(\vec{r}_i)$ are the single electron wavefunctions.

Further simplification of the above equations was performed under the assumption to account for the electron-electron interaction. It was assumed that every electron will experience only a mean-field due to the rest of the electrons in the system, this gives rise to the simplification of the many electron Hamiltonian in equation (2.2) to a single electron Fock operator given by,

$$f(\vec{r}_{i}) = -\frac{1}{2}\nabla_{i}^{2} - \sum_{K} \frac{Z_{K}}{\left|\vec{r}_{i} - \vec{R}_{K}\right|} + V^{HF}(\vec{r}_{i})$$
(2.5)

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where $f(\vec{r}_i)$ is the Fock operator, and V^{HF} is the mean field experienced by an electron. The potential V^{HF} is depedent on the other electrons all the single electron equations are essentially coupled and have to be solved numerically in a self-consistent manner. This iterative procedure has to be carried out until the wavefunction and the mean fields are self-consistent. This forms the basis of the Hartree-Fock method.

Hartree-Fock method is essentially a variational formulation, in which the trial wavefunction (basis set) is chosen that serves as the starting point for further optimization. From variational theorem, we know that the any trial wavefunction will estimate the energy higher or equal to that of the true ground state, Hartree-Fock provide an upper limit of the expected ground state energy. The best possible solution (wavefunction) can be achieved from a trial wavefunction by varying parameters until a minimum energy is obtained. The energy of the system can be expressed as,

$$E(\Psi) = \frac{\left\langle \Psi \middle| \hat{H} \middle| \Psi \right\rangle}{\left\langle \Psi \middle| \Psi \right\rangle}$$
(2.6)

where, $\left\langle \ \right\rangle$ denoted the expectation of the operator.

A notable accomplishment of Hartree-Fock method is it implements exact exchange interaction. However, it suffers a major drawback, which is the complete absence of electron correlation which is a consequence of the use of the mean field approximation to account for electron-electron Coulombic interaction. Many methods were proposed to overcome this drawback and can be collectively categorized as Post Hartree-Fock methods.

2.4 POST HARTREE-FOCK METHOD

It was realized that the absence of the electron correlation can allow two electrons to get extremely close to each other without a penalty to the overall energy of the system. One of the primary objectives of the post Hartree-Fock methods is to account for the electron correlation that is implemented as an average repulsion in the Hartree-Fock (HF) method. Many ideas were put forth for this purpose and a few of the widely used methods will be discussed in brief in this section.

A. Configuration Interaction (CI)

In order to account for the electron correlation in the HF framework, CI uses a sum of Slater determinant as opposed a single determinant used in HF.

$$\left|\Psi\right\rangle = c_{0}\left|\Psi_{0}\right\rangle + \sum_{r,a}c_{a}^{r}\left|\Psi_{a}^{r}\right\rangle + \sum_{r$$

where $|\Psi_a^r\rangle$ is formed by replacing the spin-orbital *a* by *r* in the Slater determinant $|\Psi_0\rangle$. These additional determinants are also known as the excitations from the reference HF Slater determinant. Each of these additional determinants in equation 20

(2.7) are known as "configurations", therefore the method is termed as "configuration interaction". The strength of CI lies in its general form that can be extended to excited states of a given system. However, this method is computationally very exhaustive rendering its application restricted to very small systems. If the expansion includes all possible types of configurations are employed, then it is known as "Full CI". Many variations and improvements are developed for CI and are used in specific cases; however they are built on a common principle.

B. Møller-Plesset Perturbation (MP) Theory

MP treats the exact Hamiltonian of a system that includes electron correlation as the sum of the HF Hamiltonian and a small perturbation to it. It can be written as,

$$\hat{H} = \hat{H}_0 + \lambda \hat{H}'$$
(2.8)

where λ is an arbitrary parameter and H, H_0, H' are the exact, unperturbed and perturbation Hamiltonian. The corrections are obtained through the application of Rayleigh- Schrödinger perturbation theory. These corrections are added to the HF energies to obtain exact energies that include electron correlation.

C. Coupled Cluster (CC)

CC also utilizes multiple Slater determinants for account for the electron correlation. Unlike CI, CC relies on an exponential ansatz, to write the exact wavefunction as follows:

$$\left|\Psi\right\rangle = e^{T} \left|\Psi_{0}\right\rangle \tag{2.9}$$

Where T is an excitation operator or the cluster operator, that produces excited Slater determinant, thus making the exact $|\Psi\rangle$ a linear combination of the HF wavefunction $(|\Psi_0\rangle)$. The exponential term can be expanded in terms of Taylor's series to improve on the accuracy of the calculation. Inclusion of higher order terms however, comes with a huge computational cost. Also, variations of the CC have been proposed.

2.5 DENSITY FUNCTIONAL THEORY (DFT)

In 1927, immediately after Schrödinger proposed his wave equation, Thomas and Fermi developed a model to approximate the electron distribution in an atom. The model was proposed for a non-interacting uniform electron gas in phase space. This conceptual leap reduced the 3N degrees of freedom of a many body problem to 3, significantly reducing the order of complexity of the technique. They have shown that the kinetic energy of a many body system can be expressed a functional of the number density of electrons,

$$T_{TF}[n(r)] = C_F \int n^{\frac{5}{3}}(r) d^3r \qquad (2.10)$$

where T_{TF} is the kinetic energy, n(r) is the density of electrons and C_F is a constant that depends on the Fermi energy. Coulombic interactions were implemented from classical

terms in the Thomas-Fermi model. Corrections to the kinetic energy functional were proposed by Weizsäcker in 1935,

$$T[n(r)] = C_F \int n^{\frac{5}{3}}(r) d^3r + \frac{1}{8} \frac{\hbar^2}{m} \int \frac{|\nabla n(r)|^2}{n(r)} dr \quad (2.11)$$

A. Hohenberg-Kohn Theorems

The true foundations of the DFT can be dated back to Hohenberg-Kohn theorems proposed by Pierre Hohenberg and Walter Kohn in 1964,

Theorem I: "The external potential $V_{ext}(\vec{r})$, and hence the total energy, is a unique functional of the electron density $n(\vec{r})$."[22]

$$E[n(\vec{r})] = \hat{F}[n(\vec{r})] + \int n(\vec{r}) \hat{V}_{ext}(\vec{r}) d\vec{r} \qquad (2.12)$$

where, $\hat{F}[n(\vec{r})]$ is a functional of $n(\vec{r})$ only, and $E[n(\vec{r})]$ is the energy of the system.

And $\hat{F}[n(\vec{r})]$ in equation (2.12) can be written as,

$$\hat{F}\left[n\left(\vec{r}\right)\right] = \hat{T} + \hat{V}_{ee} \tag{2.13}$$

where, \hat{T} is the kinetic energy and $\hat{V}_{_{ee}}$ is the electron-electron potential.

Theorem II: "The ground state energy can be obtained variationally: the density that minimises the total energy is the exact ground state density." [22]

As a consequence of equation (2.12), we can write,

$$E[n(\vec{r})] = \left\langle \Psi_0[n(\vec{r})] \middle| \hat{H} \middle| \Psi_0[n(\vec{r})] \right\rangle$$
(2.14)

B. Kohn-Sham Approach

Although, Hohenberg-Kohn theorems provide a firm footing for DFT, it does not offer a practical way for solution to the many body problem. The Kohn-Sham formulation transforms a real fully interacting system with a fictitious non-interacting system with an effective potential that accounts for the real interactions. We can rewrite the Hohenberg-Kohn theorem with the constraint on number of electrons as follows,

$$\delta\left[\hat{F}\left[n(\vec{r})\right] + \int n(\vec{r})V_{ext}(\vec{r})d^{-}r + \mu\left(\int n(\vec{r})d^{-}r - N\right)\right] = 0$$
where,

$$\mu = \frac{\delta\hat{F}\left[n(\vec{r})\right]}{\delta n(\vec{r})} + V_{ext}(\vec{r}) \quad a \quad n \quad d\hat{F}\left[n(\vec{r})\right] = T\left[n(\vec{r})\right] + E_{H}\left[n(\vec{r})\right] + E_{xc}\left[n(\vec{r})\right]$$

$$E_{H}\left[n(\vec{r})\right] = \frac{1}{2}\iint \frac{n(\vec{r})n(\vec{r}')}{|\vec{r}-\vec{r}'|} d\vec{r}d\vec{r}' \quad and \quad \mu = \frac{\delta T\left[n(\vec{r})\right]}{\delta n(\vec{r})} + V_{KS}\left[n(\vec{r})\right]$$

$$V_{KS}\left[n(\vec{r})\right] = V_{ext}\left[n(\vec{r})\right] + V_{H}\left[n(\vec{r})\right] + V_{xc}\left[n(\vec{r})\right]$$

$$Also,$$

$$V_{H}\left[n(\vec{r})\right] = \frac{\delta E_{H}\left[n(\vec{r})\right]}{\delta n(\vec{r})} = \int \frac{n(\vec{r})}{|\vec{r}-\vec{r}'|} d\vec{r}' \quad and \quad V_{H}\left[n(\vec{r})\right] = \frac{\delta E_{H}\left[n(\vec{r})\right]}{\delta n(\vec{r})}$$

$$(2.15)$$

Assuming a non-interacting electron gas the wavefunction Ψ_{KS} can be written as,

$$\Psi_{KS} = \frac{1}{\sqrt{N!}} \det \left[\psi_1(\vec{r}_1) \psi_2(\vec{r}_2) \psi_3(\vec{r}_3) \dots \psi_N(\vec{r}_N) \right] \quad (2.16)$$

Ground state density can be obtained by solving, N single electron Schrödinger equations,

$$\left[-\frac{1}{2}\nabla^{2}+V_{KS}\left(\vec{r}\right)\right]\psi_{i}\left(\vec{r}\right)=\varepsilon_{i}\psi_{i}\left(\vec{r}\right)$$
(2.17)

where, ε_i is a lagrange multiplier that ensures orthonormality of single electron wavefunctions $\psi_i(\vec{r})$, the density is constructed from $\psi_i(\vec{r})$ as,

$$n(\vec{r}) = \sum_{i} \left| \psi_{i}(\vec{r}) \right|^{2}$$
(2.18)

The above substitution into Schrödinger equations will lead to solution for energy and electron wavefunction but $E_{xc}[n(\vec{r})]$ is unknown at this point. The exact form of the exchange-correlation are unknown, so with the aid of approximation one can attempt to solve the equation (2.17). The following sections will deal with some of the widely used approximations in DFT.

C. Local Density Approximation (LDA)

LDA is the simplest approximation that works well for solid systems, it was proposed by Hohenberg and Kohn. The exchange-correlation (E_{XC}) is approximated from an equivalent homogenous electron gas with a density $n(\vec{r})$. The exchange was proposed by Dirac for Thomas-Fermi model and the correlation is calculated from interpolation of known extremes of high and low density values obtained from quantum monte carlo calculations. E_{XC} is given by,

$$E_{XC}^{LDA}\left[n(\vec{r})\right] = \int n(\vec{r}) \varepsilon_{xc}^{\text{hom}}\left[n(\vec{r})\right] d^{-1}$$

where,
$$\varepsilon_{X}\left[n(\vec{r})\right] = -\frac{3}{4} \left(\frac{9}{4\pi^{2}}\right)^{\frac{1}{3}} \frac{1}{r_{s}}$$
(2.19)

where, $\varepsilon_{xC}^{\text{hom}}$ is the exchange-correlation for a homogenous gas, and r_s is the wignerseitz radius and $\varepsilon_x[n(\vec{r})]$ is the exact exchange as given by Dirac.

D. Generalized Gradient Approximation (GGA)

GGA is an improvement over LDA and assumes that E_{XC} depends on density and its gradient, an analytic term the correction or the gradient term is also known as an enhancement factor. Equation (2.20) shows the functional form of GGA and as an example the exchange term in PW91 is also shown,

$$E_{xc}^{GGA} \left[n(\vec{r}) \right] = \int n(\vec{r}) \varepsilon_{xc}^{\text{hom}} \left[n(\vec{r}) \right] F_{xc} \left[n(\vec{r}), \nabla n(\vec{r}) \right] d^{-}r$$
where,
$$F_{x}^{PW91} \left[n(\vec{r}) \right] = \frac{1 + 0.19645s \sinh(7.7956s) + (0.2743 - 0.15084e^{-100s^{2}})s^{2}}{1 + 0.19645c \sinh^{-1}(7.7956s) + 0.004s^{4}}$$
(2.20)

Chapter 3

Electronic Properties of Zig-Zag Carbon Nanotubes

Using a first-principles gradient corrected density functional approach, we present a comprehensive study of the geometry and energy band gap in moderate-gap zig-zag semi-conducting (*n*,0) carbon nanotubes (CNT) to resolve some of the conflicting findings. Up to (8,0), curvature induced distortions leads to a strong deviation in energy band gap (E_g) derived from a simple zone folding picture of grapheme based on tight binding calculation. From (10,0) onwards, the gap dependence on the radius of the tube can be explained surprisingly well with the zone-folding scheme of the graphene bandstructure, if the trigonal shape of the equi-energy lines around the **K**-point is properly taken into account. Our extensive first principle calculations confirm that the (*n*,0) CNTs fall into two distinct classes depending upon *n* mod 3 equal to 1 (smaller band gaps) or 2 (larger gaps). The amplitude of the gap oscillations, arising from $\sigma - \pi$ mixing, decreases from *n* = 10 to *n* = 17. From *n* = 19 onwards, the gap follows a $\frac{1}{d}$ behavior predicted from the simple tight binding π – model with decaying amplitude.

distinct classes: for $n \mod 3 = 1$ or 2, changing E_g by ~100 meV for 1% strain in each case.

3.1 INTRODUCTION

A Carbon nanotube (CNT) is a one dimensional (1-D) nanostructured material, which has been the focal point of research over the past decade for intriguing applications ranging from nanoelectronics to chemical and biological sensors. The geometry of the carbon nanotube is uniquely described by a chiral vector $(\vec{C}):\vec{C} = n\vec{a} + m\vec{b}$, denoted by a pair of indices (n, m) that connect the two crystallographically equivalent sites on the graphene sheet. Soon after their discovery and characterization [5], the potential of this tubular structure was realized by theoretical work [23-27], which showed that the single wall CNT can be categorized into three types; metallic, small gap semiconducting, and moderate gap semiconducting based on their chirality's. It was proposed that the single wall CNT would exhibit metallic character if $\left(\frac{n-m}{3}\right)$ is an

integer, and a moderate gap semiconductor in all other cases. Furthermore, these early tight-binding based theoretical calculations also predicted that the E_g in a moderate gap semiconducting carbon nanotube (SCNT) is inversely proportional to its diameter [28] and monotonically decreases with the increase of diameter of the tube. This unique dependence of electronic properties of CNT on their diameter and chirality's, which has spawned great interest in this material, was confirmed later by the pioneering 28

experimental work that measured electronic properties of CNT [29-32] . These experiments used scanning tunneling microscope to probe the explicit dependence of chirality's and diameter on the electronic properties reported by theory. Both the experiments confirmed the earlier theoretical predictions with accuracy of ± 0.05 nm in measured diameter, and ± 0.3 eV in measured E_g. It should be noted that the band gap in SCNT is expected to be of the order of ~ 0.5 eV.

However, over the years, conflicting relationships have been reported on the exact dependence of the E_g of the SCNT on its diameter. Previous conclusions about monotonic $\frac{1}{d}$ dependence law in SCNT have been corrected. For smaller *n* the trigonal shape of the equi-energy lines around the **K**-point of the graphene Brillouin zone (BZ) ("trigonal warping" [33]) needs to be taken into account. Yorikawa *et. al.* [34] have shown that a third order Taylor expansion of the energy dispersion relation around **K**-point leads to the equation for E_g , which depends on the chirality of the tubes (more general analytic expression have been given later by Reich *et. al.* [35]). In later papers, an empirical parameter (γ) was used to account for the *curvature* effect which changes not only the *overlap* between π orbitals but causes *mixing* between π and σ orbitals [36]. For a (*n*,0) SCNT, the energy band gap is given by:

$$E_{g} = \frac{2\pi}{3} \gamma_{0} \left[\frac{1}{n} + (-1)^{n \mod 3} \gamma \frac{2\pi}{\sqrt{3}} \frac{1}{n^{2}} \right]$$
(3.1)

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where, E_g is the energy band gap, γ_0 (=2.53eV) is a parameter, *n* is the chiral index of a SCNT.

Tight binding predictions formed the basis for identification of chirality's of SCNT and interpretation of experimental results [37]. Spectrofluorimetric measurements were used in conjunction with resonant Raman data [37] to show that SCNT follow two distinct trends depending on $(n-m) \mod 3$ equal to 1 or 2 respectively. Following the experimental work, a first principle generalized gradient approximation study reported significant deviations from the simple tight binding predictions for tubes with radius smaller than 3.5 Å (n= 7,8), but confirmed results for larger n. The band gap for n mod 3 equal 2 class is higher than the other class [38]. D'yachkov and Hermann [39] used a linear augmented cylindrical wave (LACW) method to show that the band gap in SCNTs is oscillatory in nature depending on $(n-m) \mod 3$ equal to 1 or 2 but reached opposite conclusions for the two classes: the $n \mod 3 = 1$ class has larger gaps than the nmod3 = 2. Fantini *et. al.* [40, 41] determined the electronic transistion energies of several nanotubes with different chiralities using stokes and anti-stokes dependence of resonant Raman spectroscopy, and confirmed the existence of two classes of SCNT, depending on (2n+m) mod 3 equal to 1 or 2 respectively. Telg *et. al.* [42, 43] reported the evidence of two classes of SCNT based on $(n-m) \mod 3$; they interpreted their results based on three nearest neighbor tight binding model proposed by Reich et al. [44]. Again, very recently, Kozinsky and Marzari [45], have reported a different trend in the band gap for SCNTs. They have used first-principles plane wave based density functional approach and found a monotonic decrease in E_g with the increase of diameter (from (10,0) to (17,0)) as suggested by early tight-binding work that did not account for the trigonal shape of equi-energy lines around **K**-point, in contrast to the non-monotonic variation of E_g with diameter reported by several groups in the last few years [35, 38, 39]. Thus far, no consistent effort is made to resolve this important issue that is central to the assignment of chirality's of CNT.

3.2 METHODOLOGY

In this study, we have used a consistent and systematic approach to address this controversial picture. Using exhaustive ab-initio density functional computations for SCNTs up to (41,0), we show that the energy band gaps in zig-zag SCNTs indeed deviate from a simple $\frac{1}{d}$ dependence to the diameter. Our calculations are performed using periodic density functional method, which involves generalized gradient (GGA) approximation for the exchange and correlation within the framework of Perdew-Wang 91 formalism [46, 47]. We have used the Vienna *ab-initio* Simulation Package (VASP) [48] to carry out the calculations. To construct the 1-dimensional (*n*,0) nanotube structure within the periodic approach, we placed the one unit cell of the (*n*,0) in a tetragonal lattice with the tube parallel to the z-axis. The longitudinal translational vector (along z- axis) was varied from 4.25 Å to 4.28 Å to find the optimal z-translation

based on minimal total energy. The other two sides of the unit cell are chosen in such a way that the inter-wall distance between the tubes for different diameter is kept fixed at ~11 Å. This large inter-wall separation is used to ensure negligible interaction between the nanotube and its images along x, and y-direction. The geometries of the moderate gap SCNT are found to be sensitive to the number of *k*-points used to sample the Brillouin Zone (BZ), we have used 1x1x7 *k*-point mesh (Monkhorst-Pack) for optimization purposes. The minimum force criterion of 0.01 eV/Å is used for individual atom during the structural relaxation. The convergence threshold for energy is taken to be 10^{-6} eV. Wehave tested the convergence for E_g ; for example, in the case of (8,0) SCNT, a 1x1x1 *k*-point (1 irreducible *k*-point) predicts a 0.7242 eV band gap, a 1x1x7 *k*-point (4 irreducible *k*-points) mesh yielded 0.591 eV for the band gap, which is changed to 0.5904 eV with 1x1x11 *k*-point mesh (7 irreducible *k*-points). The plane wave cutoff is taken to be 286.74 eV and kept fixed for all SCNT with different diameters.

3.3 **RESULTS AND DISCUSSIONS**

First we comment on the stability of these SCNT, we have calculated the curvature energy per atom for optimized SCNT. Cohesive energy per atom is calculated as,

$$E_c = \frac{\left(E_{NT} - E_{NT}^{\infty}\right)}{N}$$
 where E_{NT} is energy of nanotube; E_{NT}^{∞} is the energy of a CNT

with ∞ diameter (graphene), and N is the total number of atoms in the nanotube. The

curvature energy is found to increase with the increase in diameter, saturating at ~ 25 Å diameter of the SCNT. These results are consistent with previous reported values obtained from *ab-initio* calculations as a measure of the stability of nanotubes [38].

Figure 3.1 shows the results for Kohn-Sham direct energy band gap as a function of their diameter indicating deviation from a simple monotonic decrease in band gap with increase in diameter of the SCNT. Up to (8,0), the strong curvature distortions change the simple picture derived from the properties of graphene. From (10,0) on, the gap dependence on the radius of the tube can be explained surprisingly well with the simple relation derived from tight binding calculations and the zone-folding of the graphene that accounts for the trigonal shape of the equi-energy lines around the **K**-point. Our first-principles calculations confirm that the (*n*,0) SCNT fall into two classes depending upon *n* mod 3 equal to 1 (smaller band gaps) or 2 (larger gaps). The amplitude of the gap oscillations, enhanced through the curvature induced $\sigma - \pi$ mixing, decreases from (10,0) to (17,0). From *n* = 19 onwards, corresponding to a radius of ~15Å, the gap's *d*-dependence roughly follows the $\frac{1}{d}$ behavior predicted from the simple tight binding π – model with decaying amplitude of oscillations.

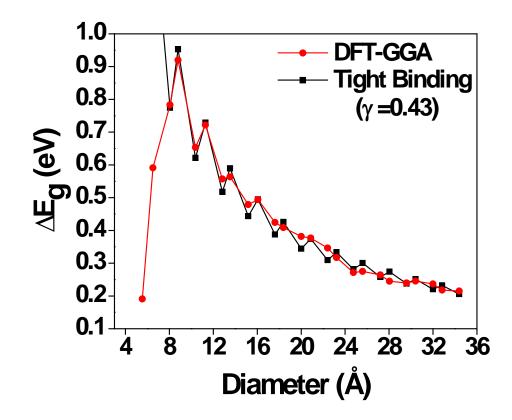


Figure 3.1 Energy band gap (E_g) as a function of the diameter of the SCNT, the circles show the predictions from density functional theory within GGA and the squares represent predictions from a tight binding model with a parameter $\gamma = 0.43$

A distinction in the trends of the two classes of SCNT is observed based on the values of $n \mod 3$. Within each class of SCNT the band gap decreases monotonically with increasing diameter beyond the initial curvature dominated region (n < 8). Figure 3.2 shows the energy band structures for three representative CNT's. This figure confirms the band gap of the SCNT's being oscillatory. Each energy band around the Fermi level in the Figure 3.2 is doubly degenerate.

For smaller n (10 to 17) the trigonal shape of the equi-energy lines around the **K**-point of the graphene BZ ("trigonal warping" [33]) needs to be taken into account. Yorikawa *et. al.* [34] have shown that a third order Taylor expansion of the energy dispersion relation around **K**-point leads to the equation for energy band gap, which depends on the chirality of the tubes (more general analytic expressions have been given later by Reich *et. al.* [35]) :

$$E_{g} = \gamma_{0} d_{C-C} \left[\frac{1}{r} + (-1)^{p} \frac{1}{12} \cos(\theta) \frac{1}{r^{2}} \right]$$
$$= \frac{2\pi}{3} \gamma_{0} \left[\frac{1}{n} + (-1)^{p} \frac{1}{12} \cos(\theta) \frac{2\pi}{3} \frac{1}{n^{2}} \right]$$
(3.2)

where, E_g is the energy band gap, γ_0 is a parameter, d_{C-C} is the carbon-carbon bond length, *n* is the chiral index of a SCNT, θ is the chiral angle ($\theta=0^\circ$ for zig-zag SCNT) and $p = n \mod 3$.

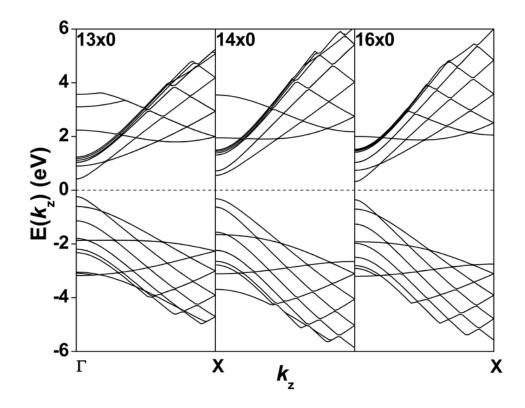


Figure 3.2 Energy band structure of three representative SCNT (13,0), (14,0) and (16,0) respectively. The dotted line at zero represents the Fermi energy level

For zig-zag tubes ($\cos\theta = 1$), maximum trigonal warping effect is expected. In the presence of warping, equation (3.2) predicts that the energy band gap for "mod 1" class is reduced (k_{vic} , the point in the projected BZ of grapheme closest to **K**-point which determines the gap in CNT, approaches **K** from the **M**-point outside the first BZ). In case of "mod 2" class the gap becomes larger (k_{vic} approaches **K** from Γ -point). This same effect, of course, explains the splitting of the van Hove singularities in the *n* mod 3 = 0 or metallic cases: k_{vic} coincides with **K**-point and leads to the metallic state; the

energies at $k_{vic} \pm = \frac{4\pi}{3a_0} \pm \frac{2\pi}{na_0}$ are no longer the same and the corresponding van Hove singularities in the density of states split [33]. In later papers, it was suggested to replace $\frac{1}{12}$ in Equation (3.3) by a parameter γ [36]. A larger γ would increase the effect of gap reduction (mod 1 class) and gap increase (mod 2 class), thus defining the amplitude of these gap oscillations:

$$E_{g} = \frac{2\pi}{3} \gamma_{0} \left[\frac{1}{n} + (-1)^{n \mod 3} \gamma \frac{2\pi}{\sqrt{3}} \frac{1}{n^{2}} \right]$$
(3.3)

where γ would empirically take into account the *curvature* effect which changes not only the *overlap* between π orbitals but causes *mixing* between π and σ orbitals.

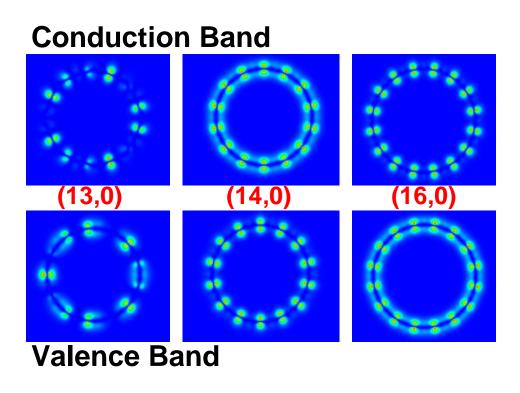


Figure 3.3 Band decomposed charge density at the Γ -point for (13,0), (14,0) and (16,0)

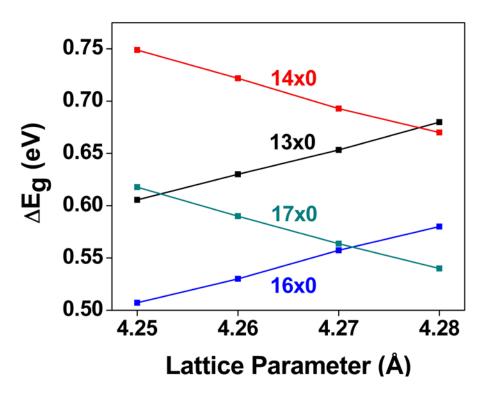


Figure 3.4 Energy band gap (E_g) as a function of the lattice parameter along the longitudinal axis (z-axis) of the CNT

Yorikawa *et. al.* [36] showed that γ is determined by $\left| \frac{V_{pp\pi}}{V_{pp\sigma}} \right|$ alone (where $V_{pp\pi}$ and $V_{pp\sigma}$

are tight bindings parameters for π and σ bonding orbitals respectively), independent of the other tight binding parameters (see Figure 3.2 in [36]), and that the mixing between

σ and π orbitals increases γ to ~ 0.43 for $\left| \frac{V_{pp\pi}}{V_{pp\sigma}} \right| = 3$ from its π-orbital-only graphene

value of $\frac{1}{12}$ (= 0.08333) and thus enhances the chirality dependence of the gap and the amplitude of the gap oscillations for between the "mod 1" and "mod 2" semiconductors. The predictions from this model are also plotted in Figure 3.1.

The energy bands around the Fermi energy are primarily of π and π^* in nature for the valence and conduction band respectively. We analyzed the band decomposed charge density at the Γ -point for the three SCNT's (Figure 3.3). It can be seen from the Figure 3.3 that the valence band in (13,0) and (16,0) show a bonding character with electron cloud smeared between atoms along the circumference which is more evident in (16,0). The conduction band in this class ($n \mod 3 = 1$) shows more of an anti-bonding character with electron clouds highly localized around the atoms. In case of (14,0) i.e. $n \mod 3 = 2$ class show an opposite trend of localized electron cloud in the valence band and a more banding character in the conduction band.

We have varied the lattice parameter along the axis of the SCNT (z-axis) from 4.25Å to 4.28 Å, for all the SCNTs, to find the influence of longitudinal strain on the energy band gap (Figure 4). The band gap in the two different classes of SCNT found to exhibit opposite trends; the band gap for $n \mod 3 = 1$ increases with increase in the z-axis translation. For $n \mod 3=2$, the band gap found to decrease with the increase in z-translation. Again this confirms two classes of SCNT. Furthermore, it also suggests an optimal z-translation is crucial for obtaining correct feature of the band gap oscillation.

We believe the absence of band gap oscillation reported by Kozinsky and Marzari [45] could be due to this effect, which might have been overlooked during structural optimization.

A study by Capaz *et. al.* utilizing frozen-phonon scheme to understand the temperature dependence of band gap in SCNT through electron-phonon coupling also reported the existence of two classes of SCNT [49]. This study has shown that the two classes arise from the difference in sign of the e-p coupling associated with low-energy optical phonons. The *n* mod 3 = 2 class of SCNT exhibits a non-monotonic relationship of the energy band gap (E_g) with increasing temperature. The existence of two classes of SCNT was also inferred from the electron-phonon (e-p) coupling matrix elements that indicate sign alteration [50] between the two classes. They have shown that the e-p coupling is stronger for zig-zag than for armchair nanotubes. A recent experimental study utilizing electron diffraction with Rayleigh scattering techniques to measure electronic and optical properties of CNT confirms the two family of SCNT based on (*n*-*m*) mod 3 equal to 1 or 2 [51]. This study is the first experimental evidence of the distinct class behavior based on the n mod 3 values unlike the previous experimental work which relied on theoretical work for interpretation of data [51].

We have varied the lattice parameter along the axis of the SCNT from 4.25Å to 4.28 Å, to find the influence of longitudinal strain on the E_g (Fig. 3.4). The E_g in the two different classes of SCNT found to exhibit opposite trends; the band gap for $n \mod 3 =$

1 increases with increase in the z-axis translation. For *n* mod 3=2, the band gap is found to decrease with the increase in z-translation. Again this reinforces the existence of two distinct classes of SCNT. It also suggests an optimal z-translation is crucial for obtaining correct feature of the E_g . We found that the longitudinal strain changes band gap by ±110 meV for 1% strain; for *n* mod 3=1, the gap increases, and for *n* mod 3=2, it decreases. These *ab-initio* results are in agreement with earlier tight binding predictions that report $\Delta E_g = \pm 3\gamma_0 (1+\nu)\sigma$, where σ is the fractional change in length along the strain axis and ν is the Poisson ratio of the material. For ν =0.2 and γ_0 =3eV, $\Delta E_g =$ 108meV for σ = 0.01 (1% strain).

Table 3.1 summarizes the values reported in the literature for E_g for SCNT. The first row is the E_g calculated from the current study, which is in good agreement with the values reported for (7,0) to (14,0) of Ref. [38]; LDA result for (8,0) of Ref. [52]; (10,0) and (11,0) of Ref. [34, 36]. Also, our results match qualitatively for (10,0) to (14,0) of Ref. [23]. We believe the absence of band gap oscillation reported in Ref. [45] is a consequence of non-optimal z-translation leading to spurious strains in CNT. It should be noted that the trend in E_g obtained from a crude single *k*-point sampling of the BZ during structural optimization will yield persistent oscillations of E_g from n=11onwards, as observed in Ref. [39]. The discrepancy between the current results and the tight binding values reported for (7,0) and (8,0) [23, 36, 52] can be attributed to the strong curvature effect that is not included in these tight-binding models . The experimental values in Table 3.1 are calculated from a π -electron model that does not account for $\sigma-\pi$ mixing. At smaller diameters, the subtle deviation in values from Ref. [29] is due to the use of π -electron model for diameter assignment that does not account for trigonal shape of the equi-energy lines around the **K**-point. We see better agreement with results at larger diameters from Ref. [30] as the influence of $\sigma-\pi$ mixing is negligible in this regime. It was reported that a strong curvature poses great difficulty in accurate measurement of the chiral angel in Ref. [30] and could be responsible for a significant deviation in E_g for (11,0). A recent experimental study utilizing electron diffraction with Rayleigh scattering techniques to measure electronic and optical properties of CNT confirms the two family of SCNT based on (*n-m*) mod 3 equal to 1 or 2 [51].

3.4 SUMMARY

In summary, we have used *ab-initio* gradient corrected density functional computations to investigate the dependence of the energy band gap in zig-zag SCNT on the diameter of the tube. We confirm the existence of two classes of SCNT based on $n \mod 3$ equal to 1 or 2. Within each class the band gap is found to decay monotonically with the increase of diameter. Up to (8,0), a strong curvature distortions lead to strong deviation from a simple picture derived from the properties of graphene. From (10,0) on, the gap dependence on the radius of the tube can be explained surprisingly well with a simple relation derived from early tight binding calculations and the zone-folding of the graphene bandstructure. If the trigonal shape of the equi-energy lines around the K-43

point is properly taken into account, our extensive first principle calculations confirm that the zig-zag semi-conducting carbon nanotubes (n,0) fall into two classes depending upon n mod 3 equal to 1 (smaller band gaps) or 2 (larger gaps). The origin of strong oscillation arises from the alternating bonding and anti-bonding character of the valance bands between the two classes of SCNTs. We also found, the transition from semi-conducting to metallic behavior occurs at ~ (43,0), with a gap of ~0.15 eV. This allows us to set a new upper limit for the diameter of the SCNT to ~40 Å, beyond which we would not observe any single wall zig-zag SCNT.

<i>n</i>	7	8	10	11	13	14	16	<u>1</u> 7				
Ab-initio												
E_{g}	0.19	0.59	0.78	0.92	0.65	0.72	0.56	0.56				
Ref. [45]	0.48	0.57	0.91	0.77	0.72	0.63	0.61	0.53				
Ref. [38] GGA	0.24	0.64	0.764	0.939	0.63	0.74	-					
Ref. [52] LDA	0.09	0.62	-	-	-	-	-					
Tight Binding												
Ref. [36]	1.11	1.33	0.87	0.96								
Ref. [52]	1.04	1.19	-	-	-	-	-					
Ref. [23]	1.0	1.22	0.86	0.89	0.69	0.7	-					
Experiment												
Ref. [29]			$0.9{\pm}0.0.05^{a}$	0.78 ± 0.07^{a}								
Ref. [30]				$1.9{\pm}0.05^{b}$			0.5 ± 0.05^{b}	$*0.55 \pm 0.05^{b}$				
			γ_{γ}	1								

Table 3.1 Energy band gap (Eg) as a function of the chirality of zig-zag SCNT. The first row under *ab-initio* presents the data from

the current study obtained from DFT-GGA

^a Data obtained from Figure 3 (c) of Ref. [29] $E_g = \frac{2\gamma_0 d_{C-C}}{d}$

^b Data obtained from Table I of Ref. [30] for d=1.4Å and chiral angle 30° (zig-zag), E_g calculated similar to ^a

* Reported chiral angle 25°, with an accuracy of $(\sim 1^{\circ})$

Chapter 4

Origin of Metallic Behavior in Multiwall Carbon Nanotubes

Following the discovery of CNT many applications have been proposed for its use, each relied on its unique electrical and mechanical properties. However, based on the structure, in particular, the presence of multiple concentric rolled up graphene sheets can be used to classify the nanotubes as SWCNT or multi-wall CNT (MWCNT). Chapter 3 provides a detailed study on the nature of the electronic properties of single walled zig-zag semi conducting (n,0) carbon nanotubes. It was found that the zig-zag (n,0) SWCNTs can be classified based on $n \mod 3$ value. They are metallic if $n \mod 3 = 0$ and semiconducting otherwise. Also, the single walled SCNT can be further classified into two classes based on upon $n \mod 3$ equal to 1 (smaller band gaps) or 2 (larger gaps). But semiconducting behavior for MWCNT (more than 3 concentric tubes) has been seldom reported in previous studies.

4.1 METHODOLOGY

In this chapter, we report the results from extensive calculations of electronic properties of multiple wall CNTs. Using *ab-initio* density functional computations for various nanotubes, we show that the zig-zag MWCNT do not exhibit semiconducting behavior beyond three walls. Our calculations are performed using periodic density functional method, which involves generalized gradient (GGA) approximation for the exchange and correlation within the framework of Perdew-Wang 91 formalism [46, 47]. We have used the Vienna *ab-initio* Simulation Package (VASP) [48] to carry out the calculations. To construct the 1-dimensional nanotube structure within the periodic approach, we placed the one unit cell of the concentric SWCNT in a tetragonal lattice with the tube parallel to the z-axis. It has been shown in previous studies that MWCNTs with intertube separation close to the interlayer separation in graphitic are more stable [53]. Some experiments have shown that different interlayer spacing is probable [54-56]; in the current study we restrict our study to MWCNT with separation close to ~ 3.5 Å. The longitudinal translational vector (along z- axis) was varied from 4.25 Å to 4.28 Å to find the optimal z-translation based on minimal total energy. The other two sides of the unit cell were chosen in such a way that the inter-wall distance between the tubes for different diameter is kept fixed at ~11 Å. This large inter-wall separation is used to ensure negligible interaction between the nanotube and its images along x, and ydirection. The minimum force criterion of 0.01 eV/Å is used for individual atom during the structural relaxation.

The convergence threshold for energy is taken to be 10^{-6} eV. We have tested the convergence for E_g; for example, in the case of (16;7,0) which represents (7,0) inside (16,0) double-walled CNT (DWCNT), a 1x1x1 *k*-point (1 irreducible *k*-point) predicts a 0.2069 eV band gap, a 1x1x5 *k*-point (3 irreducible *k*-points) mesh yielded 0.06 eV for the band gap, which is changed to 0.04 eV with 3x3x11 *k*-point mesh (16 irreducible *k*-points). The plane wave cutoff is taken to be 286.74 eV and kept fixed for all MWCNT with different diameters.

We have also tested the convergence with cohesive energy per atom for (16;7,0) and the results are plotted in Figure 4.1. It can be seen that a minimum of 3 irreducible k-points are required for accurate prediction in structure and related properties. As discussed in detail in Chapter 3, the single wall (n,0) CNT fall into two classes depending on the value of $n \mod 3 = 1$ or 2. We have calculated the energy band gap for various combinations of (n,0) SWCNT for inner and outer wall of DWCNT. Figure 4.2 – 4.8 shows the energy band structure for various combinations of the SWCNT with different energy band gaps. Figure 4.2 and 4.3 show the band structure of DWCNT with (7,0) as the inner wall. A (7,0) is a semi-metallic SWCNT with Eg ~ 0.2eV, however, when it is the inner shell of a DWCNT leads to overall metallicity of the structure.

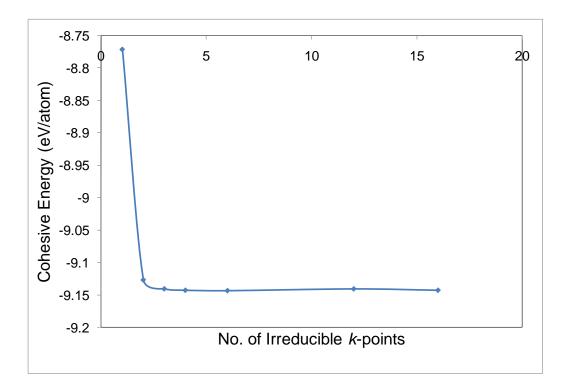


Figure 4.1 Cohesive energy per atom of (16;7,0) as a function of number of irreducible

k-points used in structural optimization

4.2 **RESULTS AND DISCUSSIONS**

This section presents the results obtained from electronic structure calculation of DWCNT and MWCNT for different combinations. As described in Chapter 3, the SWCNT can be semi-conducting, semi-metallic or metallic. Different SWCNT such as (7,0), (8,0), (10,0) and (11,0) were chosen as the inner wall for the current. For the outer wall, (16,0), (17,0), (19,0), (20,0) and (26x0) were considered. The SWCNT

combination for DWCNT MWCNT was chosen to keep the interwall distance between the constituent shells close to the graphite interlayer distance.

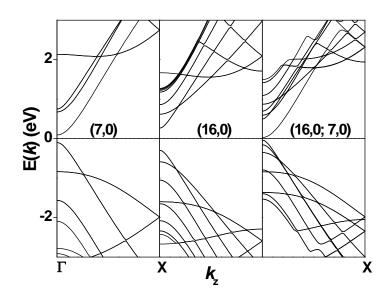


Figure 4.2 Energy band structure of (7,0), (16,0) and (16;7,0) (left to right). The zero represents the Fermi energy

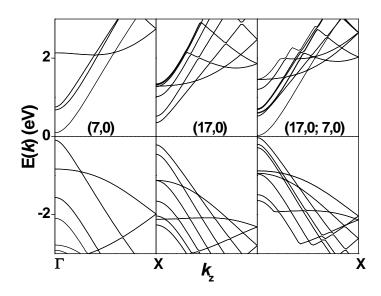


Figure 4.3 Energy band structure of (7,0), (17,0) and (17;7,0) (left to right). The zero represents the Fermi energy level.

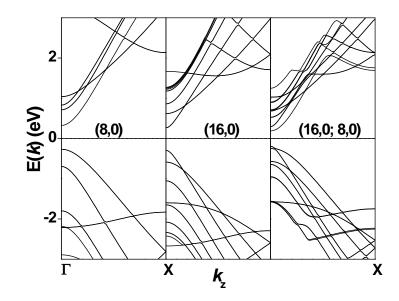


Figure 4.4 Energy band structure of (8,0), (16,0) and (16;8,0) (left to right). The zero represents the Fermi energy level.

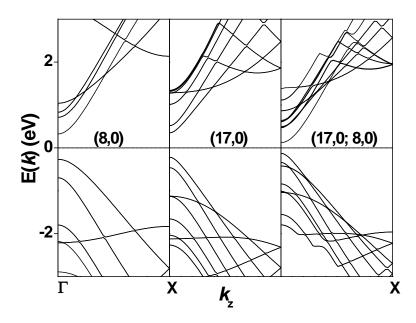


Figure 4.5 Energy band structure of (8,0), (17,0) and (17;8,0) (left to right). The zero represents the Fermi energy level.

Figure 4.4 and 4.5 show the band structure with (8,0) inner wall and (16,0) and (17,0) being the outer wall respectively. It has been shown in Chapter 3 that (8,0) has an energy band gap of ~0.6 eV and the outer wall CNT ~ 0.55 eV. Both (8,0) and (16,0) are semi-conducting CNT that have a definite energy band gap. However, the DWCNT with these SWCNT as the constituents has a band gap of ~0.4 eV, this suggests the possibility of interwall interactions that could be responsible for the reduction in the energy band gap that occurred as a consequence of adding concentric SWCNT to (8,0). In case of (17,0) as the outer wall the energy band gap was reduced to ~0.25eV; again suggesting the net band gap of the overall structure is lower than any of its constituents. Figure 4.6 – 4.9 show the band structure of different combinations of DWCNT constructed from (10,0), (11,0) as the inner tubes and (19,0), (20,0) as the outer tubes respectively.

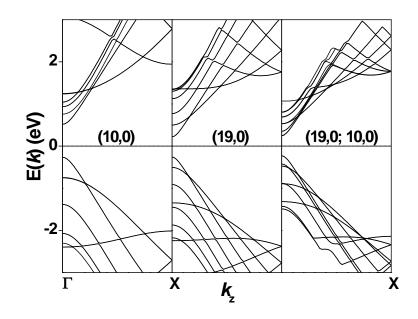


Figure 4.6 Energy band structure of (10,0), (19,0) and (19;10,0) (left to right). The zero represents the Fermi energy level.

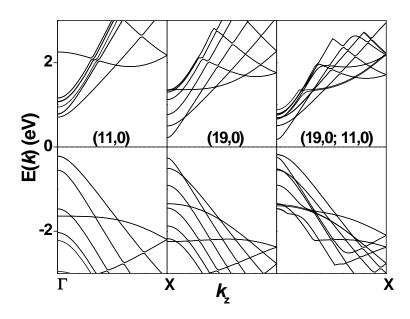


Figure 4.7 Energy band structure of (11,0), (19,0) and (19;11,0) (left to right). The zero represents the Fermi energy level.

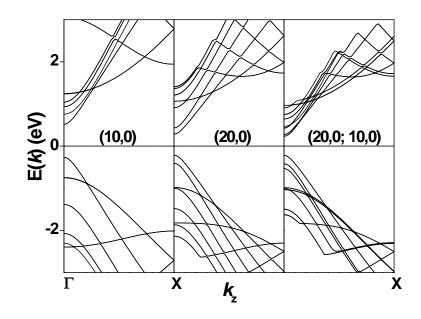


Figure 4.8 Energy band structure of (10,0), (20,0) and (20;10,0) (left to right). The zero represents the Fermi energy level.

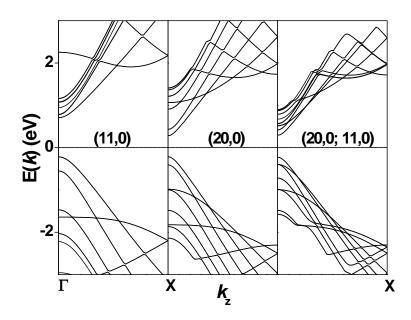


Figure 4.9 Energy band structure of (11,0), (20,0) and (20;11,0) (left to right). The zero represents the Fermi energy level.

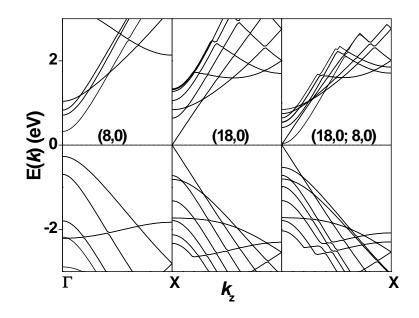


Figure 4.10 Energy band structure of (8,0), (18,0) and (18;8,0) (left to right). The zero represents the Fermi energy level.

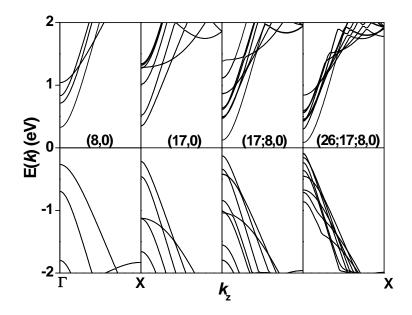


Figure 4.11 Energy band structure of (8,0), (17,0), (17;8,0) and (26;17;8,0) (left to right). The zero represents the Fermi energy level.

CNT	Cohesive Energy (E _c)	No. of atoms	E₂/atom (eV/atom)	Lattice Parameter (Å)	Band Gap (eV)					
7x0	-251.9108	28	-8.99681429	4.26	0.191					
8x0	-289.8749	32	-9.05859063	4.26	0.591					
10x0	-365.2914	40	-9.132285	4.27	0.7831					
11x0	-402.8091	44	-9.15475227	4.26	0.92					
16x0	-589.4975	64	-9.21089844	4.27	0.5573					
17x0	-626.6993	68	-9.21616618	4.27	0.5637					
19x0	-701.109	76	-9.22511842	4.27	0.4791					
20x0	-738.279	80	-9.2284875	4.26	0.4941					
25x0	-924.0033	100	-9.240033	4.27	0.3817					
26x0	-961.14223	104	-9.24175221	4.26	0.3768					
MWCNT										
16x7	-840.925809	92	-9.14049792	4.27	0.0602					
16x8	-877.684	96	-9.14254167	4.26	0.3942					
17x7	-878.47759	96	-9.15080823	4.27	0.0552					
17x8	-916.11003	100	-9.1611003	4.26	0.2479					
18x8	-953.557807	104	-9.16882507	4.27	0.001					
19x10	-1065.8518	116	-9.18837759	4.27	0.4686					
19x11	-1101.93459	120	-9.18278825	4.27	0.354					
20x10	-1140.38461	120	-9.19320508	4.26	0.4509					
20x11	-1140.47256	124	-9.19735935	4.26	0.5165					
26x17x8	1876.723061	204	-9.199622848	4.26	0.1668					

Table 4.1 Summary of the CNT band gap calculations

Based on the results, Figure 4.2-4.11 and Table 4.1, we can conclude that the band gap for a MWCNT is always equal to the lowest or lower than the band gap of any of its constituent SWCNT. In case of (20;11,0) the band gap of the DWCNT is nearly the same as that of the (20,0). In particular, it is to be noted that the band gap for any MWCNT which has any semi-metallic or metallic SWCNT as one of its wall is always metallic.

In the current study, we have considered two cases; first the inner wall to be metallic or low band gap (7,0) and semiconducting outer walls (16,0) and (17,0) respectively. Second, the outer wall to be metallic (18,0) and the a semiconducting inner wall (8,0). From Figure 4.2, 4.3 and 4.10 it can be seen that the band gap closes at the Γ -point indicating that changes have occurred in this region of the BZ. To gain some insight into this behavior, we have investigated into the band decomposed charge density of (16;7,0) DWCNT at the Γ -point. Figure 4.12 shows the results of the wavefunction based charge density. It is known that the curvature effects in (7,0) is responsible for the lower band gap as can be seen from Figure 4.12 indicating significant $\sigma - \pi$ mixing. In case of (16,0) a small degree of $\sigma - \pi$ mixing can be seen, however in (16;7,0) DWCNT this effect is further enhanced leading to closure of band gap. This can be attributed to the perturbation in charge induced from the inner wall. It is also interesting to note that at the Γ -point of the (16;7,0) DWCNT the conduction band is almost entirely contributed from the inner wall (7,0) where as the valence band is contributed from the outer wall (16,0).

The reduction n the band gap in with the addition of concentric walls can be explained as a consequence of the following factors. The π orbitals on each of the constituent wall of the MWCNT are along the direction of the normal at the corresponding atomic sites with the exception of very small diameters where π prbital also has a σ contribution that leads to some deviation from a simple π picture. Regardless of the diameter of the CNT there is at least a lobe of π like orbital that is normal to its circumference at the atomic sites. In case of multiple walls in a CNT these π orbitals interact with each other, this can be understood from the picture of two atomic orbitals of equal energy when brought together which would otherwise be degenerate states lift degeneracy by splitting of the energy levels and this splitting leads to lowering of the energy band gap in these MWCNT. The splitting of the energy levels in case of π orbitals is of the order of 200meV that is consistent with the observation in case of the MWCNT studied for the current research. The interwall interaction can be further confirmed by analyzing the atomic charges on individual carbon atoms that reveals a small charge transfer from inner to the outer wall. In certain cases there is negligible interaction between the walls of the CNT leading to overall energy band gap being the lowest energy band gap of the constituent walls.

Conduction Band (7x0) (16,0) (16;7,0) (16;7,0) Valence Band

Figure 4.12 Band decomposed charge density at the Γ -point for (7,0), (16,0) SWCNT

and (16;7,0) DWCNT

In order to understand the behavior of MWCNT we have studied the electronic properties of a three wall zig-zag CNT (26;17;8,0), the inner most wall being (8,0) and the middle wall (17,0) and the outer wall (26,0). The individual band gaps of these SWCNT are listed in Table 4.1. Figure 4.5 and 4.11 show the band structure of the DWCNT (17;8,0) and the MWCNT (26;17;8,0), it is interesting to observe that the band gap of the MWCNT is further reduced from the DWCNT and there by inducing a semi-metallic behavior of the MWCNT. It has been shown in Chapter 3 that there exists an upper limit ~40Å beyond which one will not observe semi-conducting behavior in SWCNT. This observation in conjunction with current finding that the band gap for a MWCNT is always smaller than the band gap of the constituent SWCNT leads us to the conclusion that MWCNT with more than two walls will be either show semi-metallic or metallic behavior. The origin of this metallicity can be described based on the perturbation of charge on the individual walls leading to band gap closure.

Chapter 5

Conclusions and Recommendations

One of the central requirements for a device to operate according to predetermined design relies on *apriori* knowledge of the characteristics of the components. Numerous applications for CNTs rely on its novel electrical properties and experimental determination of their chiralities and measurement of their diameters has been a challenge. These characteristics are crucial to its overall performance as they can vary significantly. A third of the single walled CNTs are metallic while the rest are semiconducting. It is extremely difficult to control the chiralities of the CNTs as grown in laboratory. A vital part of the manufacture process is characterization of the synthesized tubes. The experimental measurements fall within the accuracy of the measuring techniques making it extremely difficult to make a unique characterization. However, apriori information of their properties can aide in design of reliable and efficient characterization as well as purification processes. Computational solid-state physics provides the tools to probe the properties of these materials with minimal experimental data. Computational studies in conjunction with experiments can help exploit the potential of CNTs.

5.1 SWCNT

Using a first-principles gradient corrected density functional approach, we present a comprehensive study of the geometry and energy band gaps in moderate-gap zig-zag semi-conducting (n,0) carbon nanotubes (CNT) to resolve some of the conflicting findings. Up to (8,0), a strong curvature distortions leads to a strong deviation in energy band gap (ΔE_g) derived from a simple zone folding picture of grapheme based on tight binding calculations. From (10,0) on, the gap dependence on the radius of the tube can be explained surprisingly well with the zone-folding scheme of the graphene bandstructure, if the trigonal shape of the equi-energy lines around the K-point is properly taken into account. Our extensive first principle calculations confirm that the (n,0) CNTs fall into two distinct classes depending upon n mod 3 equal to 1 (smaller band gaps) or 2 (larger gaps). The amplitude of the gap oscillations, arising from σ - π mixing, decreases from n = 10 to n = 17. From n = 19 onwards, the gap follows a $\frac{1}{4}$ behavior predicted from the simple tight binding π – model with decaying amplitude. The effect of longitudinal strain on the band gap further confirms the existence of two distinct classes: for $n \mod 3 = 1$ or 2, changing ΔE_g by ~100 meV for 1% strain in each case.

5.2 MWCNT

In order to understand the behavior of MWCNT we have studied the electronic properties of a three wall zig-zag CNT. It is interesting to observe that the band gap of the MWCNT is always lower than the its constituent SWCNT band gap there by inducing a metallic behavior of the MWCNT. It has been shown in Chapter 3 that there exists an upper limit ~40Å beyond which one will not observe semi-conducting behavior in SWCNT. This observation in conjunction with current finding that the band gap for a MWCNT is always smaller than the band gap of the constituent SWCNT leads us to the conclusion that MWCNT with multiple walls will be metallic. The origin of this metallicity can be described based on the perturbation of charge on the individual walls leading to band gap closure

5.3 **RECOMMENDATIONS**

The currents study primarily focused on zig-zag carbon nanotubes and their electronic properties, it has shown unambiguously the existence of two classes of SCNT. However, it has been proposed by other groups that the family behavior is not restricted to the z-g-zag CNTs. This also needs to be rigorously tested from *ab-initio* calculations to put it on firm footing. Also, the mechanism for such behavior in chiral CNTs could be different that the one found in zig-zag SCNT. The changes in these properties lie

within the experimental uncertainty that calls for alternate sources of verification such as Tight Binding models and accurate computational modeling.

References

- Star, A., et al., *Preparation and Properties of Polymer-Wrapped Single-Walled Carbon Nanotubes*. Angewandte Chemie International Edition in English, 2001.
 40(9): p. 1721-1725.
- Feynman, R.P., There's Plenty of Room at the Bottom An Invitation to Enter a New Field of Physics in Engineering & Science, 1960, California Institute of Technology
- Kroto, H.W., et al., C-60 Buckminsterfullerene. Nature, 1985. 318(6042): p. 162-163.
- 4. Smalley, R.E., *Discovering the Fullerenes*, in *Nobel Lecture*. 1996.
- Iijima, S., *Helical Microtubules of Graphitic Carbon*. Nature, 1991. **354**(6348):
 p. 56-58.
- Michael Ströck, *Types of Carbon Nanotubes*, 2006, Wikimedia Foundation, http://upload.wikimedia.org/wikipedia/commons/5/53/Types_of_Carbon_Nanot ubes.png, Accessed on July 10, 2008.
- Yu, M.-F., et al., *Tensile Loading of Ropes of Single Wall Carbon Nanotubes* and their Mechanical Properties. Physical Review Letters, 2000. 84(24): p. 5552.
- Yu, M.-F., et al., Strength and Breaking Mechanism of Multiwalled Carbon Nanotubes Under Tensile Load. Science, 2000. 287(5453): p. 637-640.

- Li, F., et al., *Tensile strength of single-walled carbon nanotubes directly measured from their macroscopic ropes*. Applied Physics Letters, 2000. 77(20): p. 3161-3163.
- Frankland, S.J.V., et al., *The Stress-Strain Behavior of Polymer-Nanotube Composites from Molecular Dynamics Simulation*. Composites Science and Technology, 2003. 63(11): p. 1655-1661.
- Frankland, S.J.V., et al., Modeling and Characterization of Elastic Constants of Functionalized Nanotube Materials, in Mechanical Properties of Nanostructured Materials and Nanocomposites, I. Ovid'ko, et al., Editors. 2004, Material Research Society: Warrendale, PA. p. Q9.10.1-6.
- Frankland, S.J.V., G.M. Odegard, and T.S. Gates. *The Effect of Functionalization on Double-Walled Nanotube Materials*. in *International Symposium on Clusters and Nano-Assemblies: Physical and Biological Systems*. 2003. Richmond, VA.
- Odegard, G.M., S.J.V. Frankland, and T.S. Gates. The Effect of Chemical Functionalization on Mechanical Properties of Nanotube/Polymer Composites. in 44th AIAA/ASME/ASCE/AHS Structures, Structural Dynamics, and Materials Conference. 2003. Norfolk, VA.
- Odegard, G.M., S.J.V. Frankland, and T.S. Gates, *Effect of Nanotube Functionalization on the Elastic Properties of Polyethylene Nanotube Composites*. AIAA Journal, 2005. 43(8): p. 1828-1835.

- Odegard, G.M., et al. Constitutive Modeling of Crosslinked Nanotube Materials.
 in 45th AIAA/ASME/ASCE/AHS/ASC Structures, Structural Dynamics, and Materials Conference. 2004. Palm Springs, CA.
- Baughman, R.H., A.A. Zakhidov, and W.A. de Heer, *Carbon Nanotubes--the Route Toward Applications*. Science, 2002. 297(5582): p. 787-792.
- de Heer, W.A., A. Châtelain, and D. Ugarte, A Carbon Nanotube Field-Emission Electron Source. Science, 1995. 270(5239): p. 1179-1180.
- Kong, J., et al., *Nanotube Molecular Wires as Chemical Sensors*. Science, 2000.
 287(5453): p. 622-625.
- Balasubramanian, K. and M. Burghard, *Biosensors based on carbon nanotubes*.
 Analytical and Bioanalytical Chemistry, 2006. **385**(3): p. 452-468.
- Madden, J.D., MATERIALS SCIENCE: Artificial Muscle Begins to Breathe.
 Science, 2006. 311(5767): p. 1559-1560.
- 21. Ebron, V.H., et al., *Fuel-Powered Artificial Muscles*. Science, 2006. **311**(5767):
 p. 1580-1583.
- 22. Hohenberg, P. and W. Kohn, *Inhomogeneous Electron Gas*. Physical Review, 1964. **136**.
- 23. Hamada, N., S. Sawada, and A. Oshiyama, *New One-Dimensional Conductors Graphitic Microtubules*. Physical Review Letters, 1992. **68**(10): p. 1579-1581.
- Mintmire, J.W., D.H. Robertson, and C.T. White, *Properties of Fullerene Nanotubules*. Journal of Physics and Chemistry of Solids, 1993. 54(12): p. 1835-1840.

- White, C.T., D.H. Robertson, and J.W. Mintmire, *Helical and Rotational Symmetries of Nanoscale Graphitic Tubules*. Physical Review B, 1993. 47(9): p. 5485-5488.
- 26. Jishi, R.A., et al., *Electronic and Lattice Properties of Carbon Nanotubes*.Journal of the Physical Society of Japan, 1994. 63(6): p. 2252-2260.
- 27. Dresselhaus, M.S., G. Dresselhaus, and R. Saito, *Physics of Carbon Nanotubes*.
 Carbon, 1995. **33**(7): p. 883-891.
- Saito, R., G. Dresselhaus, and M.S. Dresselhaus, *Physical Properties of Carbon Nanotubes*. 1998: World Scientific Publishing Company
- 29. Odom, T.W., et al., *Atomic structure and electronic properties of single-walled carbon nanotubes*. Nature, 1998. **391**(6662): p. 62-64.
- 30. Wildoer, J.W.G., et al., *Electronic structure of atomically resolved carbon nanotubes*. Nature, 1998. **391**(6662): p. 59-62.
- Zhang, Z. and C.M. Lieber, Nanotube structure and electronic properties probed by scanning tunneling microscopy. Applied Physics Letters, 1993. 62: p. 2792-2794
- Kim, P., et al., Electronic Density of States of Atomically Resolved Single-Walled Carbon Nanotubes: Van Hove Singularities and End States. Physical Review Letters, 1999. 82: p. 1225-1228
- Saito, R., G. Dresselhaus, and M.S. Dresselhaus, *Trigonal warping effect of carbon nanotubes*. Physical Review B, 2000. 61(4): p. 2981-2990.

- 34. Yorikawa, H. and S. Muramatsu, *Chirality Dependence of Energy Gaps of Semiconducting Nanotubules*. Solid State Communications, 1995. 94(6): p. 435-437.
- Reich, S. and C. Thomsen, *Chirality dependence of the density-of-states singularities in carbon nanotubes*. Physical Review B, 2000. 62(7): p. 4273-4276.
- Yorikawa, H. and S. Muramatsu, *Energy Gaps of Semiconducting Nanotubules*.
 Physical Review B, 1995. 52(4): p. 2723-2727.
- Bachilo, S.M., et al., *Structure-assigned optical spectra of single-walled carbon* nanotubes. Science, 2002. 298(5602): p. 2361-2366.
- 38. Gulseren, O., T. Yildirim, and S. Ciraci, *Systematic ab initio study of curvature effects in carbon nanotubes*. Physical Review B, 2002. **65**(15).
- D'yachkov, P.N. and H. Hermann, *Electronic structure and interband transitions of semi-conducting carbon nanotubes*. Journal of Applied Physics, 2004. 95(1).
- 40. Fantini, C., et al., Optical transition energies for carbon nanotubes from resonant Raman spectroscopy: Environment and temperature effects. Physical Review Letters, 2004. **93**(14): p. -.
- 41. Fantini, C., et al., One-dimensional character of combination modes in the resonance Raman scattering of carbon nanotubes. Physical Review Letters, 2004. 93(8): p. -.

- 42. Telg, H., et al., *Chirality distribution and transition energies of carbon nanotubes.* Physical Review Letters, 2004. **93**(18): p. -.
- 43. Telg, H., et al., *Chirality distribution and transition energies of carbon nanotubes*. Physical Review Letters, 2004. **93**(17): p. -.
- 44. Reich, S., et al., *Tight-binding description of graphene*. Physical Review B, 2002. **66**(3): p. -.
- 45. Kozinsky, B. and N. Marzari, *Static dielectric properties of carbon nanotubes from first principles*. Physical Review Letters, 2006. **96**(16): p. -.
- 46. Perdew, J.P., *Density-functional approximation for the correlation energy of the inhomogeneous electron gas.* Physical Review B, 1986. **33**(12): p. 8822.
- 47. Perdew, J.P. and W. Yue, Accurate and simple density functional for the electronic exchange energy: Generalized gradient approximation. Physical Review B, 1986. 33(12): p. 8800.
- 48. Department, T.P., *Vienna Ab-initio Simulation Package*.
- 49. Capaz, R.B., et al., *Temperature dependence of the band gap of semiconducting carbon nanotubes*. Physical Review Letters, 2005. **94**(3): p. -.
- Machón, M., S. Reich, and C. Thomsen, Strong electron-phonon coupling of the high-energy modes of carbon nanotubes. Physical Review B, 2006. 74: p. 205423-1 - 205423-4.
- 51. Sfeir, M.Y., et al., *Optical spectroscopy of individual single-walled carbon nanotubes of defined chiral structure*. Science, 2006. **312**(5773): p. 554-556.

- Blase, X., et al., *Hybridization Effects and Metallicity in Small Radius Carbon* Nanotubes. Physical Review Letters, 1994. 72(12): p. 1878-1881.
- 53. Okada, S. and A. Oshiyama, *Curvature-induced metallization of double-walled semiconducting zigzag carbon nanotubes*. Physical Review Letters, 2003.
 91(21): p. -.
- 54. Li, L.X., et al., Synthesis and characterization of double-walled carbon nanotubes from multi-walled carbon nanotubes by hydrogen-arc discharge. Carbon, 2005. 43(3): p. 623-629.
- 55. Ren, W.C., et al., Morphology, diameter distribution and Raman scattering measurements of double-walled carbon nanotubes synthesized by catalytic decomposition of methane. Chemical Physics Letters, 2002. **359**(3-4): p. 196-202.
- 56. Zhao, Z.G., et al., *The growth of multi-walled carbon nanotubes with different morphologies on carbon fibers*. Carbon, 2005. **43**(3): p. 663-665.

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